OPTO ELECTRONICS CHARACTERISATION

Experiment(s):

1. I-V Characteristics of - Photo diode, LED, Photo transistor, LDR

- 2. Solar cell characteristics
- 3. Opto-coupler characteristic

(For more details, procedure & manual visit: www.kamaljeeth.net)

Reference : Lab Experiments Journal vol-2, No.3, Page-8



Specifications:

Optical bench Bench length: 500 mm Scale: Yes with LC 0.1 cm Sliders & holders: 3 Material: Cast iron heavy base with leveling screw, hardened aluminium rail

Photo sensitive semi conductors

Photo transistor, LDR, Photo diode, opto-coupler and solar cell

White light source: LED lamp Output: 2 W Rated Input: 220 V/50 Hz or 110 V/60 Hz

Semiconductor diode Laser Wavelength: 625 nm (Red) Output power: 3 mW Mount: Height adjustable Power supply output: Suitable for 3 mW & 5 mW semi conductor Lasers

Opto-electronics

characteristics kit DC variable regulated power supply with coarse and fine knobs 0-12 V Continuos variable load resistor Internally connected digital volt and current meters Rated Input: 220 V/50 Hz or 110 V/60 Hz Mains cord: 3 pin

KAMALJEETH INSTRUMENTS

Address: No. 610, 5th main, 8th cross Tatanagar, Bangalore - 560092, INDIA Website: **www.kamaljeeth.net**, Email: labexperiments@kamaljeeth.net ESTD. 1990

3 years manufacturing warranty